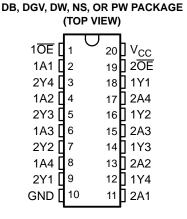
## SN74LV244AT OCTAL BUFFER/DRIVER WITH 3-STATE OUTPUTS

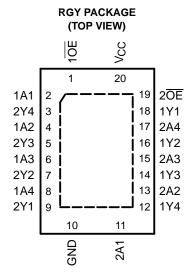
#### **FEATURES**

- Inputs Are TTL-Voltage Compatible
- 4.5-V to 5.5-V V<sub>CC</sub> Operation
- Typical  $t_{nd} = 5.4 \text{ ns at 5 V}$
- Typical V<sub>OLP</sub> (Output Ground Bounce) <0.8 V at  $V_{CC} = 5$  V,  $T_{\Delta} = 25^{\circ}$ C
- Typical  $V_{OHV}$  (Output  $V_{OH}$  Undershoot) >2.3 V at  $V_{CC}$  = 5 V,  $T_A$  = 25°C
- **Supports Mixed-Mode Voltage Operation on All Ports**

I<sub>off</sub> Supports Partial-Power-Down Mode Operation

- Latch-Up Performance Exceeds 250 mA Per **JESD 17**
- **ESD Protection Exceeds JESD 22** 
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)
  - 1000-V Charged-Device Model (C101)





#### DESCRIPTION/ORDERING INFORMATION

This octal buffer/driver is designed specifically to improve both the performance and density of 3-state memory-address drivers, clock drivers, and bus-oriented receivers and transmitters.

The SN74LV244AT is organized as two 4-bit buffers/line drivers with separate output-enable (OE) inputs. When  $\overline{OE}$  is low, the device passes data from the A inputs to the Y outputs. When  $\overline{OE}$  is high, the outputs are in the high-impedance state.

#### ORDERING INFORMATION

T <sub>A</sub>	PACKAGE <sup>(1)</sup>		ORDERABLE PART NUMBER	TOP-SIDE MARKING
	QFN – RGY	Reel of 1000	SN74LV244ATRGYR	VV244
	SOIC - DW	Tube of 25	SN74LV244ATDW	LV244AT
	301C - DVV	Reel of 2000	SN74LV244ATDWR	LV244AT
	SOP - NS	Reel of 2000	SN74LV244ATNSR	74LV244AT
-40°C to 85°C	SSOP - DB	Reel of 2000	SN74LV244ATDBR	LV244AT
		Tube of 70	SN74LV244ATPW	
	TSSOP - PW	Reel of 2000	SN74LV244ATPWR	LV244AT
		Reel of 250	SN74LV244ATPWT	
	TVSOP – DGV	Reel of 2000	SN74LV244ATDGVR	LV244AT

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



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## **DESCRIPTION/ORDERING INFORMATION (CONTINUED)**

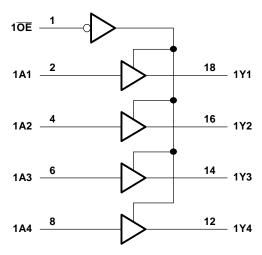
To ensure the high-impedance state during power up or power down,  $\overline{\text{OE}}$  shall be tied to  $V_{\text{CC}}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

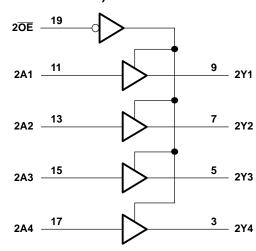
This device is fully specified for partial-power-down applications using  $I_{\text{off}}$ . The  $I_{\text{off}}$  circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

# FUNCTION TABLE (EACH 4-BIT BUFFER/DRIVER)

INPL	JTS	OUTPUT
ŌĒ	Α	Υ
L	Н	Н
L	L	L
Н	X	Z

## **LOGIC DIAGRAM (POSITIVE LOGIC)**







## SN74LV244AT OCTAL BUFFER/DRIVER WITH 3-STATE OUTPUTS

# Absolute Maximum Ratings<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT	
$V_{CC}$	Supply voltage range		-0.5	7	V	
VI	Input voltage range <sup>(2)</sup>		-0.5	7	V	
Vo	Voltage range applied to any output in the	high-impedance or power-off state <sup>(2)</sup>	-0.5	7	V	
Vo	Output voltage range applied in the high o	Output voltage range applied in the high or low state (2)(3)				
I <sub>IK</sub>	Input clamp current	V <sub>1</sub> < 0		-20	mA	
I <sub>OK</sub>	Output clamp current	V <sub>O</sub> < 0		<b>–</b> 50	mA	
Io	Continuous output current	$V_O = 0$ to $V_{CC}$		±35	mA	
	Continuous current through V <sub>CC</sub> or GND			±70	mA	
		DB package (4)		70		
		DGV package <sup>(4)</sup>		92		
	Deal and the good from a day of	DW package <sup>(4)</sup>		58	0000	
$\theta_{JA}$	Package thermal impedance	NS package <sup>(4)</sup>		60	°C/W	
		PW package <sup>(4)</sup>		83		
		RGY package <sup>(5)</sup>		37		
T <sub>stg</sub>	Storage temperature range		-65	150	°C	

- (1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.
- (3) This value is limited to 5.5 V maximum.
- (4) The package thermal impedance is calculated in accordance with JESD 51-7
- (5) The package thermal impedance is calculated in accordance with JESD 51-5.

## Recommended Operating Conditions<sup>(1)</sup>

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage		4.5	5.5	V
$V_{IH}$	High-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	2		V
V <sub>IL</sub>	Low-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V		0.8	V
VI	Input voltage		0	5.5	V
.,	Outrot valta as	High or low state	0	$V_{CC}$	V
Vo	Output voltage	3-state	0	5.5	V
I <sub>OH</sub>	High-level output current	V <sub>CC</sub> = 4.5 V to 5.5 V		-16	mA
I <sub>OL</sub>	Low-level output current	V <sub>CC</sub> = 4.5 V to 5.5 V		16	mA
Δt/Δν	Input transition rise or fall rate	V <sub>CC</sub> = 4.5 V to 5.5 V		20	ns/V
T <sub>A</sub>	Operating free-air temperature		-40	85	°C

<sup>(1)</sup> All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



### **Electrical Characteristics**

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V <sub>CC</sub>	T,	λ = 25°C	;	T <sub>A</sub> = -		UNIT	
			MIN	TYP	MAX	MIN	MAX		
V	$I_{OH} = -50 \mu A$	4.5 V	4.4	4.5		4.4		V	
V <sub>OH</sub>	$I_{OH} = -16 \text{ mA}$	4.5 V	3.8			3.8		V	
V	$I_{OL} = 50 \mu A$	4.5 V		0	0.1		0.1	V	
V <sub>OL</sub>	$I_{OL} = 16 \text{ mA}$	4.5 V			0.55		0.55	V	
I <sub>I</sub>	$V_I = 5.5 \text{ V or GND}$	0 to 5.5 V			±0.1		±1	μΑ	
I <sub>OZ</sub>	$V_O = V_{CC}$ or GND	5.5 V			±0.25		±2.5	μΑ	
I <sub>cc</sub>	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			2		20	μΑ	
$\Delta I_{CC}^{(1)}$	One input at 3.4 V, Other inputs at V <sub>CC</sub> or GND	5.5 V			1.35		1.5	mA	
I <sub>off</sub>	$V_I$ or $V_O = 0$ to 5.5 V	0			0.5		5	μΑ	
C <sub>i</sub>	$V_I = V_{CC}$ or GND			4.5				pF	

<sup>(1)</sup> This is the increase in supply current for each input at one of the specified TTL voltage levels, rather than 0 V or V<sub>CC</sub>.

## **Switching Characteristics**

over recommended operating free-air temperature range,  $V_{CC}$  = 5 V  $\pm$  0.5 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	LOAD	T,	<sub>λ</sub> = 25°C	2	MIN	MAX	UNIT
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	IVIIIV	WAX	UNIT
t <sub>PLH</sub>	A or B	B or A	C - 15 pE	2.6	5/4	7.4	1	8.5	ns
t <sub>PHL</sub>	AUID	D OI A	$C_L = 15 pF$	2.4	5.4	7.4	1	8.5	115
t <sub>PZH</sub>	ŌĒ	A or B	C - 15 pE	2.2	7.7	10.4	1	12	ns
t <sub>PZL</sub>	OE	A OF B	C <sub>L</sub> = 15 pF	2.7	7.7	10.4	1	12	115
t <sub>PHZ</sub>	ŌĒ	A or B	C <sub>L</sub> = 15 pF	2.2	3.9	7.7	1	8	
t <sub>PLZ</sub>	OE	AUID	OL = 10 pi	2.5	3.9	7.7	1	8	ns
t <sub>PLH</sub>	A or B	B or A	C <sub>L</sub> = 50 pF	4	5.9	8.9	1	9.5	ns
t <sub>PHL</sub>	AUID			4.7	5.9	8.9	1	9.5	115
t <sub>PZH</sub>	ŌĒ	A or B	C <sub>L</sub> = 50 pF	3.9	8.2	11.4	1	13	
t <sub>PZL</sub>	OE	AOIB	C <sub>L</sub> = 50 pr	4.9	8.2	11.4	1	13	ns
t <sub>PHZ</sub>	ŌĒ	A or B	C = 50 pF	3.3	8.8	11.4	1	13	
t <sub>PLZ</sub>	UE	A OF B	$C_L = 50 \text{ pF}$	3.2	8.8	11.4	1	13	ns
t <sub>sk(o)</sub>			$C_{L} = 50 \text{ pF}$			1		1	ns

# Noise Characteristics<sup>(1)</sup>

 $V_{CC} = 5 \text{ V}, C_L = 50 \text{ pF}$ 

	PARAMETER	Т	UNIT		
	PARAMETER	MIN	TYP	MAX	UNIT
V <sub>OL(P)</sub>	Quiet output, maximum dynamic V <sub>OL</sub>		0.8	1	V
$V_{OL(V)}$	Quiet output, minimum dynamic V <sub>OL</sub>		-0.8	-1	V
V <sub>OH(V)</sub>	Quiet output, minimum dynamic V <sub>OH</sub>		4		V
$V_{IH(D)}$	High-level dynamic input voltage	2			V
$V_{IL(D)}$	Low-level dynamic input voltage			0.8	V

<sup>(1)</sup> Characteristics are for surface-mount packages only.





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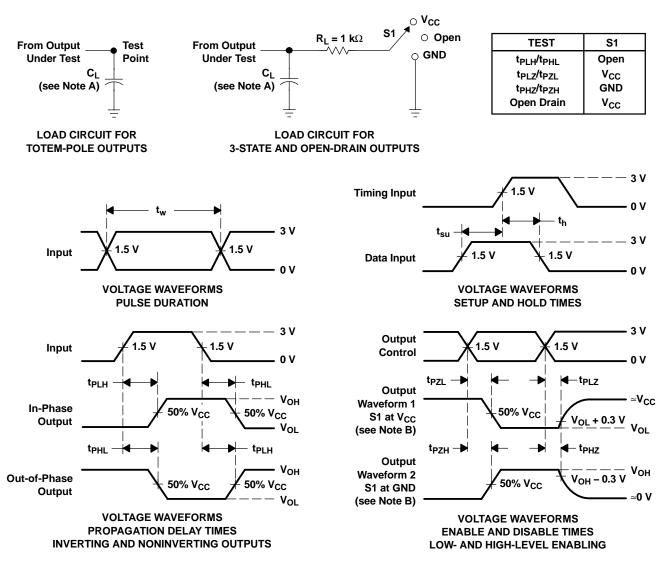
# **Operating Characteristics**

 $V_{CC} = 5 \text{ V}, T_{A} = 25^{\circ}\text{C}$ 

	PARAMETER		TEST CO	ONDITIONS	TYP	UNIT
$C_{pd}$	Power dissipation capacitance	Outputs enabled	$C_L = 50 \text{ pF},$	f = 10 MHz	8	pF



#### PARAMETER MEASUREMENT INFORMATION



NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  1 MHz,  $Z_O = 50 \Omega$ ,  $t_f \leq$  3 ns.  $t_f \leq$  3 ns.
- D. The outputs are measured one at a time, with one input transition per measurement.
- E. t<sub>PLZ</sub> and t<sub>PHZ</sub> are the same as t<sub>dis</sub>.
- F. t<sub>PZL</sub> and t<sub>PZH</sub> are the same as t<sub>en</sub>.
- G.  $t_{PHL}$  and  $t_{PLH}$  are the same as  $t_{pd}$ .
- H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuits and Voltage Waveforms

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#### **PACKAGING INFORMATION**

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
							(6)				
SN74LV244ATDWR	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LV244AT	Samples
SN74LV244ATNSR	ACTIVE	SO	NS	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	74LV244AT	Samples
SN74LV244ATPW	ACTIVE	TSSOP	PW	20	70	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LV244AT	Samples
SN74LV244ATPWR	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LV244AT	Samples
SN74LV244ATRGYR	ACTIVE	VQFN	RGY	20	3000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	VV244	Samples
SN74LV244ATRGYRG4	ACTIVE	VQFN	RGY	20	3000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	VV244	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.



## **PACKAGE OPTION ADDENDUM**

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# PACKAGE MATERIALS INFORMATION

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## TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

All differsions are norminal													
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant	
SN74LV244ATDWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1	
SN74LV244ATNSR	SO	NS	20	2000	330.0	24.4	8.4	13.0	2.5	12.0	24.0	Q1	
SN74LV244ATPWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1	
SN74LV244ATRGYR	VQFN	RGY	20	3000	330.0	12.4	3.8	4.8	1.6	8.0	12.0	Q1	

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\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LV244ATDWR	SOIC	DW	20	2000	367.0	367.0	45.0
SN74LV244ATNSR	SO	NS	20	2000	367.0	367.0	45.0
SN74LV244ATPWR	TSSOP	PW	20	2000	853.0	449.0	35.0
SN74LV244ATRGYR	VQFN	RGY	20	3000	853.0	449.0	35.0

## **MECHANICAL DATA**

# NS (R-PDSO-G\*\*)

# 14-PINS SHOWN

## PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



3.5 x 4.5, 0.5 mm pitch

PLASTIC QUAD FGLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.





PLASTIC QUAD FLATPACK - NO LEAD



- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
  2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.



PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

- 4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.





SOIC



- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.





SMALL OUTLINE PACKAGE



- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



# PW (R-PDSO-G20)

# PLASTIC SMALL OUTLINE



- All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
  C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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